

Fast CMOS 3.3V 16-Bit Register (3-State)

Product Features

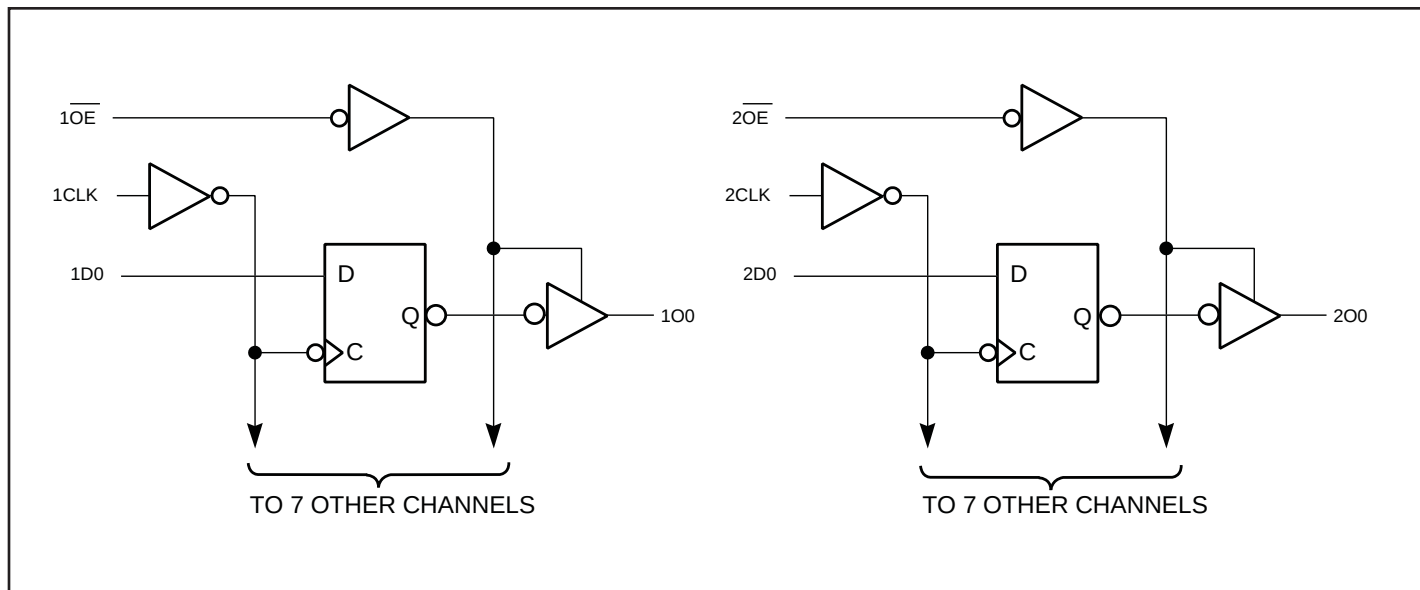
- Functionally compatible with FCT3, LVT, and 74 series 16374 families of products
- 3-state outputs
- 5V Tolerant inputs and outputs
- 2.0V-3.6V V_{DD} supply operation
- Balanced sink and source output drives (24mA)
- Low ground bounce outputs
- Power down High Impedance inputs and outputs
- Supports live insertion
- ESD Protection exceeds 2000V, Human Body Model
200V, Machine Model
- Packaging (Pb-free & Green available):
 - 48-pin 240-mil wide plastic TSSOP (A)
 - 48-pin 300-mil wide plastic SSOP (V)

Product Description

The PI74LCX16374 is a 16-bit octal register designed with 16 D-type flip-flops with a buffered common clock and 3-state outputs. The Output Enable ($\overline{xOE}$) and clock ($xCLK$) controls are organized to operate as two 8-bit registers or one 16-bit register. When $\overline{OE}$ is HIGH, the outputs are in the high impedance state. Input data meeting the setup and hold time requirements of the D inputs is transferred to the O outputs on the LOW-to-HIGH transition of the clock input.

The PI74LCX16374 can be driven from either 3.3V or 5.0V devices allowing this device to be used as a translator in a mixed 3.3/5.0V system.

Logic Block Diagram



Product Pin Description

Pin Name	Description
$\overline{xOE}$	3-State Output Enable Inputs (Active LOW)
xCLK	Clock Inputs
xDx	Data Inputs
xOx	3-State Outputs
GND	Ground
V _{DD}	Power

Truth Table

Function	Inputs ⁽¹⁾			Outputs ⁽¹⁾
	xDx	xCLK	$\overline{xOE}$	xOx
High - Z	X	L	H	Z
	X	H	H	Z
Load Register	L	↑	L	L
	H	↑	L	H
	L	↑	H	Z
	H	↑	H	Z
	X	H or L	L	O ₀

Note:

1. H = High Voltage Level, X = Don't Care,
L = Low Voltage Level, Z = High Impedance

Product Pin Configuration

$\overline{1OE}$	1	48	1CLK
1O0	2	47	1D0
1O1	3	46	1D1
GND	4	45	GND
1O2	5	44	1D2
1O3	6	43	1D3
V _{DD}	7	42	V _{DD}
1O4	8	41	1D4
1O5	9	40	1D5
GND	10	39	GND
1O6	11	38	1D6
1O7	12	37	1D7
2O0	13	36	2D0
2O1	14	35	2D1
GND	15	34	GND
2O2	16	33	2D2
2O3	17	32	2D3
V _{DD}	18	31	V _{DD}
2O4	19	30	2D4
2O5	20	29	2D5
GND	21	28	GND
2O6	22	27	2D6
2O7	23	26	2D7
$\overline{2OE}$	24	25	2CLK

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–40°C to +85°C
Supply Voltage to Ground Potential (Inputs & V _{DD} Only).....	–0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)	–0.5V to +7.0V
DC Input Voltage	–0.5V to +7.0V
DC Output Current.....	120 mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Parameter	Description		Min.	Max.	Units
V _{DD}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V _I	Input Voltage		0	5.5	
V _O	Output Voltage	HIGH or LOW state	0	V _{DD}	
		3-state	0	5.5	
I _{OH} /I _{OL}	Output Current	V _{DD} = 3.0V - 3.6V		±24	mA
		V _{DD} = 2.7V		±12	
T _A	Operating Temperature		–40	85	°C
Δt/ΔV	Input Edge Rate	V = 0.8V - 2.0V, V _{DD} = 3.0V	0	10	ns/V

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{DD} = 2.7\text{V}$ to 3.6V)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Units
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0			V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW Level				0.8	
V_{OH}	Output HIGH Voltage	$V_{DD} = 2.7 - 3.6$	$I_{OH} = -0.1\text{mA}$	$V_{DD} - 0.2$			
		$V_{DD} = 2.7$	$I_{OH} = -12\text{mA}$	2.2			
		$V_{DD} = 3.0$	$I_{OH} = -18\text{mA}$	2.4			
			$I_{OH} = -24\text{mA}$	2.2			
V_{OL}	Output LOW Voltage	$V_{DD} = 2.7 - 3.6$	$I_{OL} = 0.1\text{mA}$			0.2	
		$V_{DD} = 2.7$	$I_{OL} = 12\text{mA}$			0.4	
		$V_{DD} = 3.0$	$I_{OL} = 16\text{mA}$			0.4	
			$I_{OL} = 24\text{mA}$			0.55	
V_{IK}	Clamp Diode Voltage	$V_{DD} = \text{Min.}, I_{IN} = -18\text{mA}$			-0.7	-1.2	
I_I	Input Leakage Current	$0 \leq V_I \leq 5.5\text{V}$	$V_{DD} = 2.7 - 3.6$			± 5	μA
I_{OZ}	Tri-State Output Leakage	$0 \leq V_O \leq 5.5\text{V}$ $V_I = V_{IH}$ or V_{IL}	$V_{DD} = 2.7 - 3.6$			± 5	
I_{OFF}	Power Down Disable	$V_{DD} = 0\text{V}, V_{IN}$ or $V_{OUT} \leq 5.5\text{V}$				10	
I_{DD}	Quiescent Power supply current	$V_{DD} = \text{Max.}$	$V_{IN} = \text{GND}$ or V_{DD}		0.1	10	
ΔI_{DD}	Quiescent Power supply current TTL Inputs High	$V_{DD} = \text{Max.}$	$V_{IN} = V_{DD} = 0.6\text{V}^{(3)}$			500	

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at $V_{DD} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient.
- Per TTL driven input; all other inputs at V_{DD} or GND.

Capacitance

Parameters	Description	Test Conditions	Typ.	Units
C_{IN}	Input Capacitance	$V_{DD} = \text{Open}, V_I = 0\text{V}$ or V_{DD}	3	pF
C_{OUT}	Output Capacitance	$V_{DD} = 3.3\text{V}, V_I = 0\text{V}$ or V_{DD}	3	
C_{PD}	Power Dissipation Capacitance	$V_{DD} = 3.3\text{V}, V_I = 0\text{V}$ or V_{DD} , $F = 10\text{MHz}$	20	

Switching Characteristics over Operating Range

Parameters	Description	Test Conditions	$V_{DD} = 3.3V \pm 0.3$		$V_{DD} = 2.7V$		Units
			Min.	Max.	Min.	Max.	
f_{MAX}	Maximum Clock Frequency	CL = 50pF RL = 500Ω	170				MHz
t_{PHL} t_{PLH}	Propagation Delay CP to On		1.5	6.2	1.5	6.5	ns
t_{PZL} t_{PZH}	Output Enable time		1.5	6.1	1.5	6.3	
t_{PLZ} t_{PHZ}	Output Disable time		1.5	6.0	1.5	6.2	
t_S	Setup Time		2.5		2.5		
t_H	Hold Time		1.5		1.5		
t_W	Pulse Width		3.0		3.0		
$t_{sk(0)}$	Output to Output Skew ⁽¹⁾			1.0			

Notes:

1. Skew between any two outputs, of the same package, switching in the same direction.

Dynamic Switching Characteristics ($T_A = +25^\circ C$)

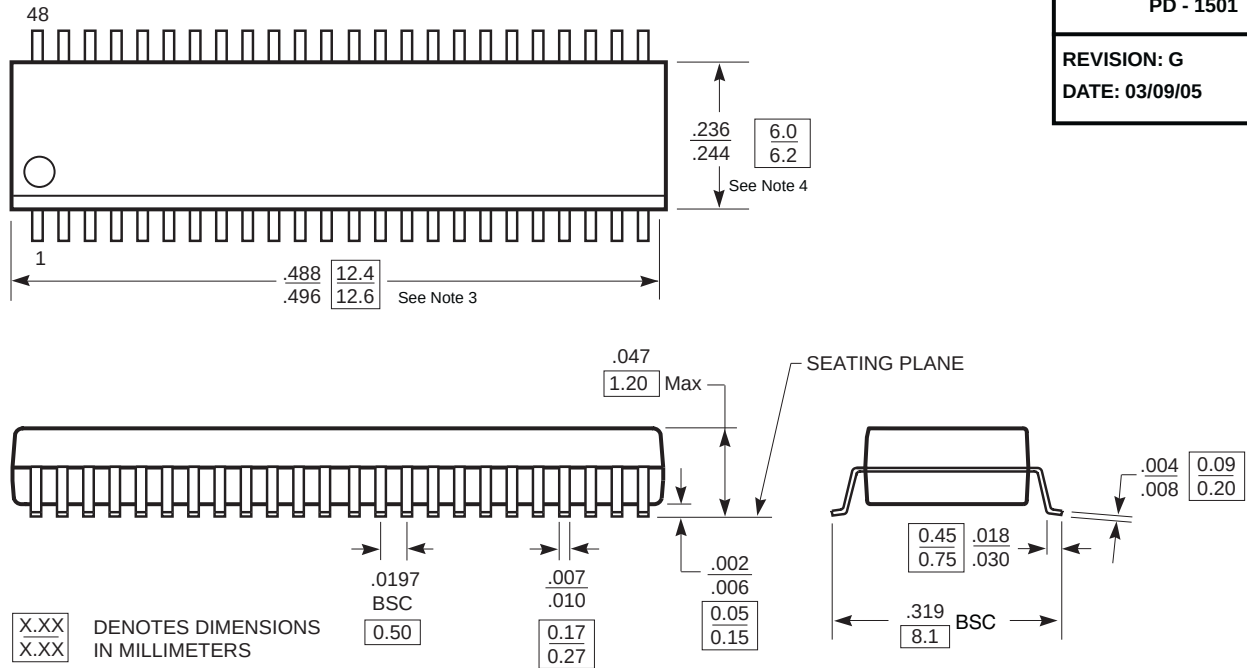
Parameters	Description	Test Conditions ⁽¹⁾	Typ.	Units
V_{OLP}	Dynamic LOW peak voltage	$V_{DD} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$	0.8	V
V_{OLV}	Dynamic LOW valley voltage			

Note:

1. Measured with n-1 outputs switching from High-to-Low or Low-to-High. The remaining output is measured in the LOW state.

DOCUMENT CONTROL NO.
PD - 1501

REVISION: G
DATE: 03/09/05



Note:

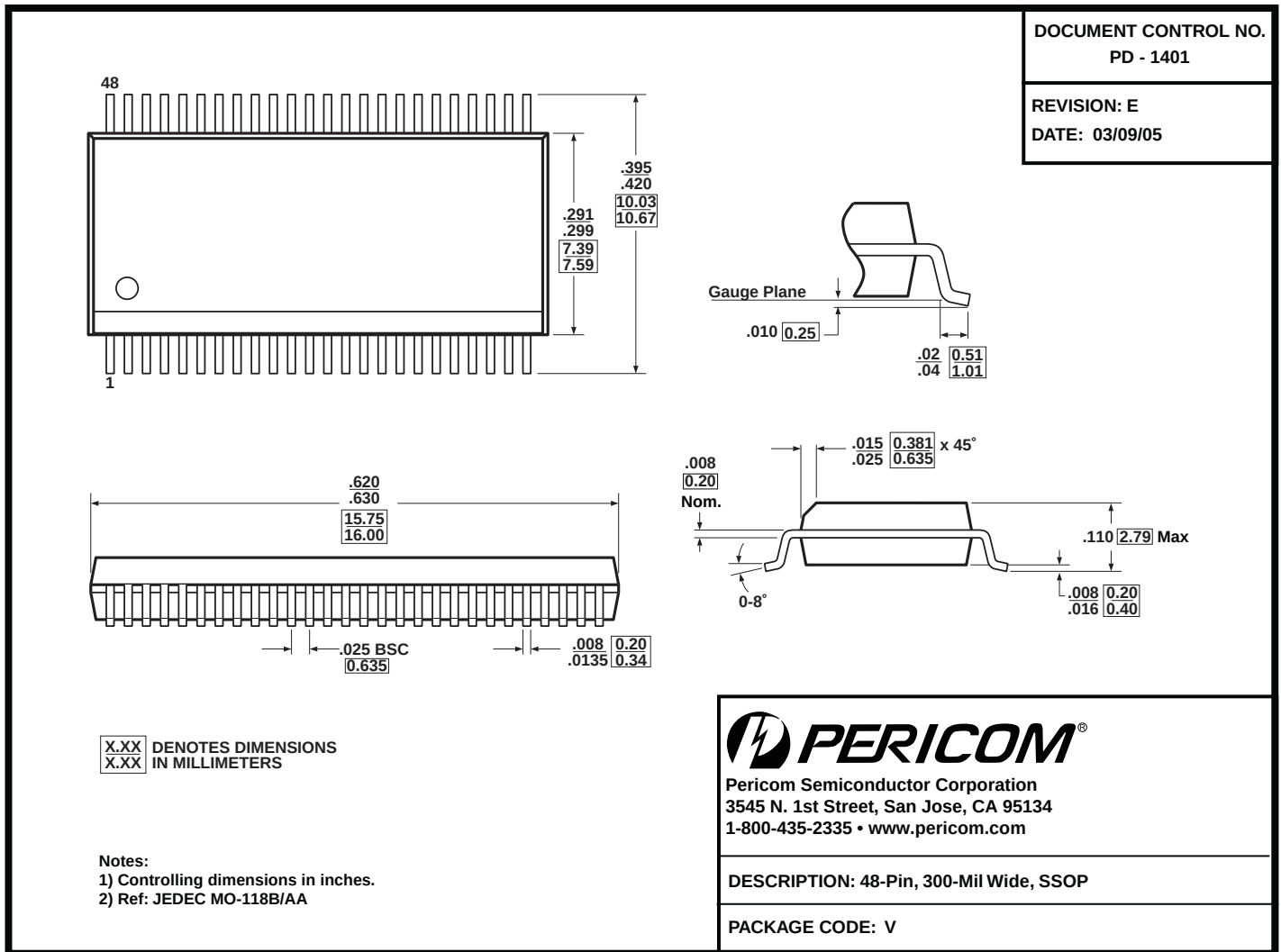
1. Controlling dimensions in millimeters.
2. Ref: JEDEC MO-153F/ED
3. Dimension does not include mold flash, protrusions or gate burrs. Mold flash, protrusions and gate burrs shall not exceed 0.15mm per side.
4. Dimension does not include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.25mm per side.



Pericom Semiconductor Corporation
3545 N. 1st Street, San Jose, CA 95134
1-800-435-2335 • www.pericom.com

DESCRIPTION: 48-Pin 240-Mil Wide TSSOP

PACKAGE CODE: A



Notes:

- For latest package info, please check: <http://www.pericom.com/products/packaging/mechanicals.php>

Ordering Information

Ordering Code	Package Code	Package Description
PI74LPT16374AAEX	A	Pb-free & Green, 48-Pin 240-mil wide Plastic TSSOP (A)
PI74LPT16374AEX	A	Pb-free & Green, 48-Pin 240-mil wide Plastic TSSOP (A)
PI74LPT16374CAEX	A	Pb-free & Green, 48-Pin 240-mil wide Plastic TSSOP (A)
PI74LPT16374CVEX	V	Pb-free & Green, 48-Pin 300-mil wide Plastic SSOP (V)
PI74LPT16374VEX	V	Pb-free & Green, 48-Pin 300-mil wide Plastic SSOP (V)

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- E = Pb-free and Green
- Adding an X suffix = Tape/Reel